# NSN 5961-01-163-6269

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-163-6269

## **Inclosure Material:**

Plastic

**Overall Length:** 

0.435 inches

## **Overall Height:**

0.105 inches

## **Overall Width:**

0.305 inches

## **Mounting Facility Quantity:**

1

## Internal Configuration:

Junction contact-darlington connected

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 40.0 breakdown

voltage, collector-to-base, emitter open

# **Current Rating Per Characteristic:**

4.00 amperes source cutoff current and 100.00 milliamperes source cutoff current

## **Power Rating Per Characteristic:**

1.5 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## Terminal Type And Quantity:

3 pin

#### **Specification Data:**

80131-release6422a professional/industrial association specification

#### Shelf Life:

N/a

# Unit Of Measure:

---

## Demilitarization:

No

## Fiig:

A110a0